

**EFFECT OF Ca ADDITION ON PIEZOELECTRIC AND DIELECTRIC
PROPERTIES IN $\text{Pb}_{0.93}\text{La}_{0.02}\text{Sr}_{0.05}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ (PLSZT) SYSTEM**

by

TUAN NUR IZZAH BINTI TUAN AB RASHID

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TABLE OF CONTENTS

	Page
ACKNOWLEDGEMENT	ii
TABLE OF CONTENTS	iii
LIST OF TABLES	viii
LIST OF FIGURES	x
LIST OF ABBREVIATIONS	xiv
LIST OF SYMBOLS	xv
ABSTRAK	xvi
ABSTRACT	xviii
CHAPTER ONE: INTRODUCTION	
1.1 Piezoelectric material	1
1.2 Problem Statement	4
1.3 Objectives	7
1.4 Scope of Study	7
CHAPTER TWO: LITERATURE REVIEW	
2.1 Ceramics	10
2.2 Electroceramics	10
2.2.1 Ceramic insulators	11
2.2.2 Dielectric ceramics	12
2.2.3 Piezoelectric ceramics	14

2.2.3(a) Piezoelectric Ceramic System	17
2.3 Lead Zirconate Titanate (PZT)	18
2.3.1 Phase Diagram of PZT	18
2.3.2 Structure of PZT	22
2.3.3 Dopant Materials and Chemical Modifications in PZT system	24
2.3.4 Effect of Sintering Parameters on properties of PZT Systems	31
2.3.5 Polarization in PZT system	33
2.3.5(a) Parameter affect the polarization	35
2.3.5(b) Effect of polarization on properties	36
2.3.6 Application of PZT ceramics	37
2.4 Dielectric Properties	39
2.4.1 Dielectric Permittivity	39
2.4.2 Loss Tangent	42
2.5 Piezoelectric Properties	43
2.5.1 Piezoelectric Coefficient, d_{33}	43
2.5.2 Electromechanical Coupling Factor, k_p	45
2.6 Design of Experiment Concept	45
2.6.1 Full Factorial	47

CHAPTER THREE: MATERIALS AND METHODOLOGY

3.1 Introduction	49
3.2 Raw Materials	49
3.2.1 Lead Oxide, PbO	49
3.2.2 Zirconium Oxide, ZrO ₂	50

3.2.3	Titanium Oxide, TiO_2	50
3.2.4	Lanthanum Oxide, La_2O_3	50
3.2.5	Strontium Carbonate, SrCO_3	50
3.2.6	Calcium Carbonate, CaCO_3	51
3.3	Methodology	51
3.3.1	Sample Formulation	51
3.3.2	Sample Preparation	53
3.3.3	Milling Process	54
3.3.4	Pressing Process	55
3.3.5	Sintering Process	55
3.3.6	Poling Process	56
3.4	Design of Experiment (DOE)	58
3.4.1	Full Factorial Experiment	60
3.5	Characterizations	61
3.5.1	X-ray diffraction (XRD)	62
3.5.2	Field Emission Scanning Electron Microscope (FESEM)	62
3.5.3	Energy Dispersive X-Ray Spectroscopy (EDX)	63
3.5.4	Apparent Solid Density and Apparent Solid Porosity Testing	64
3.5.5	Dielectric Testing	65
3.5.6	Piezoelectric Testing	65

CHAPTER FOUR: RESULTS AND DISCUSSION

4.1	Introduction	67
4.2	Raw Material Characterizations	67

4.2.1	Lead Oxide Powders, PbO	67
4.2.2	Zirconium Oxide Powders, ZrO ₂	68
4.2.3	Titanium Oxide Powders, TiO ₂	70
4.2.4	Lanthanum Oxide Powders, La ₂ O ₃	71
4.2.5	Strontium Carbonate Powders, SrCO ₃	72
4.2.6	Calcium Carbonate Powders, CaCO ₃	73
4.3	Synthesis of PLSZT	74
4.3.1	XRD Analysis	74
4.3.2	FESEM Analysis	76
4.3.3	Apparent Solid Density and Apparent Solid Porosity Analysis	77
4.3.4	Dielectric Analysis based on Full Factorial Design (DOE)	78
4.3.5	Piezoelectric Analysis based on Full Factorial Design (DOE)	80
4.4	Synthesis of Ca ²⁺ doped PLSZT (PCLSZT)	84
4.4.1	XRD Analysis	84
4.4.2	FESEM Analysis	86
4.4.3	Apparent Solid Density and Apparent Solid Porosity Analysis	89
4.4.4	Dielectric Analysis	91
4.4.5	Piezoelectric Analysis	94
4.5	Effects of Sintering Parameter on PCLSZT samples	96
4.5.1	Effects of Sintering Temperature	97
	4.5.1(a) XRD Analysis	97
	4.5.1(b) FESEM Analysis	99
	4.5.1(c) EDX Analysis	100
	4.5.1(d) Apparent Solid Density and Apparent Solid Porosity Analysis	102
	4.5.1(e) Dielectric Analysis	103

4.5.1(f) Piezoelectric Analysis	105
4.5.2 Effects of Soaking Time	108
4.5.2(a) XRD Analysis	108
4.5.2(b) FESEM Analysis	110
4.5.3(c) EDX Analysis	111
4.5.2(d) Apparent Solid Density and Apparent Solid Porosity Analysis	113
4.5.2(e) Dielectric Analysis	114
4.5.2(f) Piezoelectric Analysis	115
4.6 Summary of Research Work	117

CHAPTER FIVE: CONCLUSION AND RECOMMENDATION

5.1 Conclusion	118
5.2 Recommendation for Future Research	119

REFERENCES	120
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APPENDICES

APPENDIX A: CALCULATION OF Ca^{2+} DOPED PLSZT BASED ON STOICHIOMETRY FORMULATION

APPENDIX B: LIST OF PUBLICATION AND CONFERENCES

LIST OF TABLES

		Page
Table 2.1	A comparison of the characteristics of the hard and soft doped piezoceramic material (Moulson and Herbert, 2003)	25
Table 2.2	Common aliovalent substituents (Moulson and Herbert, 2003)	25
Table 2.3	Types of dopants in PZT and their major effect (Panda and Sahoo, 2015)	26
Table 2.4	The dielectric and piezoelectric properties of doped PZT with various dopants	28
Table 3.1	The weight of raw materials for preparing undoped PZT according to $\text{Pb}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ sample	52
Table 3.2	The weight of raw materials for preparing a PLSZT according to $\text{Pb}_{0.93}\text{La}_{0.02}\text{Sr}_{0.05}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ sample	52
Table 3.3	The weight of raw materials for preparing a PCLSZT according to $\text{Pb}_{0.93-x}\text{Ca}_x\text{La}_{0.02}\text{Sr}_{0.05}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ sample ($x=0.01$)	53
Table 3.4	The weight of raw materials for all composition to produce $\text{Pb}_{0.93-x}\text{Ca}_x\text{La}_{0.02}\text{Sr}_{0.05}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ sample	53
Table 3.5	Parameters for $\text{Pb}_{0.93-x}\text{Ca}_x\text{La}_{0.02}\text{Sr}_{0.05}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ synthesis	54
Table 3.6	Sample codes for Ca^{2+} doped PLSZT	54
Table 3.7	Sample codes of Ca^{2+} doped PLSZT sintered at three different temperatures	55
Table 3.8	Sample codes of Ca^{2+} doped PLSZT sintered at three different soaking times	56
Table 3.9	Control factors and their coded levels for 2^3 factorial designs	60
Table 3.10	DOE of poling process based on CCD by full factorial	61
Table 4.1	The bulk density and porosity data for pure PZT, PLSZT	77
Table 4.2	Dielectric permittivity of PLSZT samples	78
Table 4.3	Analysis of variance ANOVA for dielectric permittivity	79
Table 4.4	Second analysis of variance ANOVA for dielectric permittivity	80

Table 4.5	Experimental design matrix of CCD poling parameter and its corresponding response for piezoelectric coefficient, d_{33}	81
Table 4.6	Analysis of variance ANOVA for piezoelectric properties	81
Table 4.7	Second analysis of variance ANOVA for piezoelectric properties	82

LIST OF FIGURES

		Page
Figure 1.1	Flowchart of overall process	9
Figure 2.1	The internal field of dielectric polarization (Powles, 1953)	13
Figure 2.2	(a) The direct and (b) the indirect piezoelectric effects: (i) contraction; (ii) expansion. The broken lines indicate the original dimensions (Moulson and Herbert, 2003).	14
Figure 2.3	Behaviour of piezoceramic material. (a) Non-polarized state, (b) polarized state and (c) electric applied after poling (Jaffe, 2012)	15
Figure 2.4	Phase diagram of $\text{Pb}(\text{Zr}_{1-x}\text{Ti}_x)\text{O}_3$ (PZT) solid solution (Jaffe, 1971)	19
Figure 2.5	Morphotropic phase boundary in PZT phase diagram (Kounga et al., 2008)	20
Figure 2.6	Dielectric and piezoelectric properties of the PbTiO_3 - PbZrO_3 solid solution (Jaffe, 1971)	21
Figure 2.7	Perovskite structure (Jordan and Ounaies, 2001)	22
Figure 2.8	Perovskite structure of ABO_3 . Unit cell in the cubic phase, tetragonal phase, orthorhombic phase and rhombohedral phase (Prewitt and Jones, 2011)	23
Figure 2.9	Motion of 90° and 180° ferroelectric domain wall structures (Pérez et al., 2010)	29
Figure 2.10	Mechanism in sintering (McColm, 1994)	31
Figure 2.11	Densification followed by grain growth (Barsoum and El-Raghy, 1999)	32
Figure 2.12	Crystalline structure of piezoelectric ceramics (Patel, 2011)	34
Figure 2.13	Mechanism of polar domain before and after polarization (Patel, 2011)	34
Figure 2.14	Schematic of a piezoelectric fan (Acikalin et al., 2004)	38
Figure 2.15	A parallel-plate capacitor (a) without dielectric material and (b) with dielectric material (Callister and Rethwisch, 2011)	41

Figure 2.16	Schematic diagram of force/charge relationship on piezoelectric elements. (a) Element in 33 mode and (b) Element in 31 mode (Mo et al., 2009)	44
Figure 2.17	Design experiment based on DOE process (Antony, 2014)	47
Figure 3.1	Poling process	57
Figure 3.2	Synthesis of undoped PZT and PLSZT	57
Figure 3.3	Synthesis of Ca^{2+} doped PLSZT (PCLSZT)	58
Figure 3.4	Process flow for synthesis of PZT doped with La^{3+} and Sr^{2+} for optimize the poling parameter	59
Figure 4.1	XRD pattern of PbO powders	68
Figure 4.2	FESEM result for PbO powders	68
Figure 4.3	XRD pattern of ZrO_2 powders	69
Figure 4.4	FESEM result for ZrO_2 powders	69
Figure 4.5	XRD pattern of TiO_2 powders	70
Figure 4.6	FESEM result for TiO_2 powders	70
Figure 4.7	XRD pattern of La_2O_3 powders	71
Figure 4.8	FESEM result for La_2O_3 powders	71
Figure 4.9	XRD pattern of SrCO_3 powders	72
Figure 4.10	FESEM result for SrCO_3 powders	72
Figure 4.11	XRD pattern of CaCO_3 powders	73
Figure 4.12	FESEM result for CaCO_3 powders	73
Figure 4.13	XRD pattern of undoped PZT and PLSZT	74
Figure 4.14	Intensity values at (101) peak between undoped PZT and PLSZT	75
Figure 4.15	2θ values shifted at (101) peak between undoped PZT and PLSZT	76
Figure 4.16	SEM microstructure for (a) PZT and (b) PLSZT pellet samples at 5K magnification	76

Figure 4.17	Mean effect plot for each level on piezoelectric coefficient based on (a) electric field, (b) temperature and (c) time of poling process	83
Figure 4.18	XRD patterns of PLSZT ceramics with increasing CaCO_3 content: (a) $x=0.0$ mol%, (b) $x=0.003$ mol% CaCO_3 , (c) $x=0.005$ mol% CaCO_3 , (d) $x=0.008$ mol% CaCO_3 , (e) $x=0.01$ mol% CaCO_3 , (f) $x=0.03$ mol% CaCO_3 , (g) $x=0.05$ mol% CaCO_3 and (h) $x=0.1$ mol% CaCO_3	84
Figure 4.19	Intensity values at (101) peak correspond to Ca compositions	85
Figure 4.20	2θ values shifted at (101) peak correspond to Ca compositions	86
Figure 4.21	SEM microstructure for (a) PLSZT, (b) PCLSZT0.003, (c) PCLSZT0.005, (d) PCLSZT0.008, (e) PCLSZT0.01, (f) PCLSZT0.03, (g) PCLSZT0.05 and (h) PCLSZT0.10 of pellet samples	87
Figure 4.22	Average grain size of each sample	88
Figure 4.23	The bulk density of undoped PLSZT and Ca doped PLSZTs	90
Figure 4.24	The porosity for undoped PLSZT and Ca doped PLSZTs	91
Figure 4.25	Dielectric permittivity with increasing the Ca compositions	92
Figure 4.26	Tangent loss with increasing the Ca compositions	93
Figure 4.27	The piezoelectric coefficient of undoped PLSZT and Ca doped PLSZTs	94
Figure 4.28	The electromechanical coupling factor of undoped PLSZT and Ca doped PLSZTs	96
Figure 4.29	XRD pattern of PCLSZT0.005 samples sintered at three different temperatures	98
Figure 4.30	Intensity values at (101) peak correspond to sintering temperature	99
Figure 4.31	FESEM microstructure for PCLSZT0.005 after different sintering temperature (a) 1100 °C, (b) 1200 °C and (c) 1300 °C at 5K magnification	99
Figure 4.32	EDX profile and element compositions presence according to sintering temperature (a) 1100 °C, (b) 1200 °C and (c) 1300 °C	101

Figure 4.33	The bulk density and porosity against sintering temperature of PCLSZT0.005	103
Figure 4.34	Dielectric permittivity of PCLSZT0.005 sintered at three different sintering temperatures	104
Figure 4.35	Tangent loss of PCLSZT0.005 sintered at three different sintering temperatures	105
Figure 4.36	Piezoelectric coefficient of PCLSZT0.005 samples sintered at three different temperatures	106
Figure 4.37	Electromechanical coupling factor value for PCLSZT0.005 samples sintered at three different temperatures	107
Figure 4.38	XRD pattern of PCLSZT0.005 sintered at three different soaking times	109
Figure 4.39	Intensity values at (101) peak according to sintering duration	109
Figure 4.40	FESEM micrograph of PCLSZT0.005 sintered at three different soaking times (a) 2 hours, (b) 3 hours and (c) 4 hours at 5K magnification	110
Figure 4.41	EDX profile and element content presence according to soaking time (a) 2 hours, (b) 3 hours and (c) 4 hours	111
Figure 4.42	The bulk density and porosity against soaking times of PCLSZT0.005	113
Figure 4.43	Dielectric permittivity of PCLSZT0.005 sintered at 1200 °C for three different soaking times	114
Figure 4.44	Tangent loss of PCLSZT0.005 sintered at 1200 °C for three different soaking times	115
Figure 4.45	Piezoelectric coefficient of PCLSZT0.005 samples sintered at three different soaking times	116
Figure 4.46	Electromechanical coupling factor value for PCLSZT0.005 samples sintered at three different soaking times	117

LIST OF ABBREVIATIONS

PZT	Lead zirconate titanate
PLSZT	Lead lanthanum strontium zirconate titanate
PCLSZT	Lead calcium lanthanum strontium zirconate titanate
Pb	Lead
Zr	Zirconium
Ti	Titanium
La	Lanthanum
Sr	Strontium
Ca	Calcium
MPB	Morphotropic phase boundary
XRD	X-ray diffraction
FESEM	Field emission scanning electron microscopy
DOE	Design of experiment
RSM	Respond surface methodology
rpm	Revolution per minutes

LIST OF SYMBOLS

λ	Wavelength
d_{33}	Piezoelectric coefficient
k_p	Electromechanical coupling factor
ϵ_r	Dielectric permittivity
$\tan \delta$	Dielectric loss
T_m	Melting temperature
T	Temperature
E_f	Electric field
t	Time
M_d	Weight of dry pellet
M_s	Weight of suspended pellet
M_w	Weight of saturated pellet
wt %	Weight percent
mol %	Concentration percent

KESAN PENAMBAHAN Ca KE ATAS SIFAT-SIFAT PIEZOELEKTRIK DAN DIELEKTRIK DALAM SISTEM $\text{Pb}_{0.93}\text{La}_{0.02}\text{Sr}_{0.05}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ (PLSZT)

ABSTRAK

Plumbum zirkonat titanat (PZT) adalah bahan piezoelektrik yang paling banyak digunakan di kalangan seramik. Gabungan La^{3+} dan Sr^{2+} terdop PZT (PLSZT) menunjukkan peningkatan dalam sifat-sifat piezoelektrik dan dielektrik yaitu pemalar piezoelektrik (d_{33}), faktor pengganding elektromekanik (k_p) dan pemalar dielektrik (ϵ_r). Walau bagaimanapun, d_{33} dan k_p masih lagi menunjukkan bacaan yang rendah untuk aplikasi peranti elektronik. Untuk meningkatkan d_{33} and k_p , proses pendopan dan pengkutuban telah dikaji. Dalam kajian ini, seramik $\text{Pb}_{0.93}\text{La}_{0.02}\text{Sr}_{0.05}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ (PLSZT) telah disintesis menggunakan pengisar bebola planet berkuasa tinggi selama 40 jam dan disinter pada suhu $1200\text{ }^\circ\text{C}$ selama 3 jam. Parameter pengkutuban (suhu, medan elektrik dan masa) telah dikaji berdasarkan reka bentuk eksperimen (RBE) untuk mengkaji kesan parameter pengkutuban ke atas sifat-sifat piezoelektrik dan dielektrik bagi PLSZT. Selain itu, satu dopan baru (CaCO_3) bagi PLSZT telah dikaji diikuti dengan parameter pensinterannya ($1100\text{ }^\circ\text{C}$ hingga $1300\text{ }^\circ\text{C}$ selama 2 hingga 4 jam) untuk meningkatkan lagi sifat-sifat piezoelektrik dan dielektrik. Parameter pengkutuban yang optimum telah menunjukkan bacaan d_{33} dan ϵ_r yang baik dan masing-masing adalah 320 pC/N dan 1660 . Parameter pengkutuban yang optimum adalah pada $T = 140\text{ }^\circ\text{C}$, $E_f = 4\text{ kV/mm}$ dan $t = 20\text{ min}$. Ca^{2+} terdop PLSZT (PCLSZT) menunjukkan berlakunya peningkatan d_{33} , k_p dan ϵ_r pada penambahan Ca yang lebih rendah. Sifat-sifat piezoelektrik dan dielektrik yang optimum diperolehi pada 0.005 mol\% Ca (PCLSZT0.005) yang disinter pada suhu $1200\text{ }^\circ\text{C}$ selama 3 jam dengan $d_{33} = 430$

pC/N, $k_p = 0.5866$, $\epsilon_r = 2450$ dan $\tan \delta = 0.0426$. Kesimpulannya, penambahan Ca^{2+} telah berjaya meningkatkan sifat-sifat piezoelektrik dan dielektrik PLSZT.

EFFECT OF Ca ADDITION ON PIEZOELECTRIC AND DIELECTRIC PROPERTIES IN $\text{Pb}_{0.93}\text{La}_{0.02}\text{Sr}_{0.05}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ (PLSZT) SYSTEM

ABSTRACT

Lead zirconate titanate (PZT) is a piezoelectric material which is most widely used in ceramics. La^{3+} and Sr^{2+} co-doped PZT (PLSZT) shows the improvement in piezoelectric and dielectric properties which were piezoelectric coefficient (d_{33}), electromechanical coupling factor (k_p) and dielectric permittivity (ϵ_r). However, the d_{33} and k_p still indicated a lower value for electronic device applications. In order to improve d_{33} and k_p , the doping process and poling behaviour were investigated. In this research, $\text{Pb}_{0.93}\text{La}_{0.02}\text{Sr}_{0.05}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ (PLSZT) ceramic was synthesized by high energy planetary ball milling for 40 hours and sintered at 1200 °C for 3 hours. The poling parameters (temperature, electric field and time) were studied based on design of experiment (DOE) in order to investigate the effect of poling parameter towards the piezoelectric and dielectric properties for PLSZT. Besides, a new dopant (CaCO_3) for PLSZT was studied followed by sintering parameters (1100 °C to 1300 °C for 2 to 4 hours) for further improving their piezoelectric and dielectric properties. The optimum poling parameter shows a good d_{33} and ϵ_r which were 320 pC/N and 1660, respectively. Poling parameters were optimized at $T = 140$ °C, $E_f = 4$ kV/mm and $t = 20$ min. Ca^{2+} doped PLSZT (PCLSZT) show that enhancement of d_{33} , k_p and ϵ_r occurred at lower Ca addition. Optimum piezoelectric and dielectric properties were obtained at 0.005 mol% CaCO_3 (PCLSZT0.005) sintered at 1200 °C for 3 hours with $d_{33} = 430$ pC/N, $k_p = 0.5866$, $\epsilon_r = 2450$ and $\tan \delta = 0.0426$. In conclusion the addition of Ca^{2+} successfully increased the piezoelectric and dielectric properties of PLSZT.

CHAPTER ONE

INTRODUCTION

1.1 Piezoelectric material

Advance ceramics have provided greater control over aspects of composition and microstructure that govern physical properties. Such control makes it possible to tailor ceramics to fulfill special chemical, thermal, mechanical, and electrical requirements no other material can satisfy. Indeed, advanced ceramics have played critical roles in the development of new technology such as computers and telecommunications and they will continue to play a leading role in the technologies of the future. Their properties can be tailored to operation as insulators, ferroelectric materials, highly conductive ceramics, electrodes as well as sensors and actuators (Miclea et al., 2002; Shindo and Narita, 2012).

The piezoelectric material is a material that can create electricity when subjected to a mechanical stress also known as direct piezoelectric effect. They will also work in reverse, which is generating a strain by the application of an electric field and is known as indirect piezoelectric effect (Jordan and Ounaies, 2001). These electroceramics do not produce high piezoelectric behaviour due to the fact that the ceramics have a structure that consists of random orientations of grain. Therefore, these materials exhibit a polarized electrostatic effect where the electricity is applied in static material in order to rearrange the domain orientation in the grain. Thus, the ceramic must be polarized to align the orientation of the grain structures. The most commonly known piezoelectric materials are lead zirconate titanate (PZT) and barium titanate (BaTiO_3). Lead zirconate titanate is considered one of the most economical piezoelectric element, hence it is used in a lot of applications. As for the

second one, barium titanate, it is a piezoelectric ceramic which is usually replaced by lead zirconate titanate for piezoelectricity (Frantti and Fujioka, 2011).

Piezoelectric ceramics, usually based on lead zirconate titanate (PZT) which is an intermetallic inorganic compound with the chemical formula $\text{Pb}(\text{Zr}_x\text{Ti}_{1-x})\text{O}_3$ ($0 \leq x \leq 1$). PZT is a ceramic perovskite material that shows a marked piezoelectric effect, meaning that the compound is used in a number of practical applications in the area of electroceramics such as sonars, ultrasonic cleaners, buzzers, accelerometers, ultrasonic motors and piezo transformers (Carter and Norton, 2007). Piezoelectric ceramics based on PZT are widely used for numerous applications in the microelectronics industry. In order to tailor the physical properties required in specific applications, PZT ceramics were usually doped with small amounts of other oxides. The compositions nearing the morphotropic phase boundary (MPB) exhibit a good piezoelectric activity. MPB exhibits good piezoelectric properties because the boundary consists of two phases (tetragonal and rhombohedral) which can enhance domain wall mobility and facilitate polarization rotation. Thus, improve the dielectric and piezoelectric properties. Therefore the Zr/Ti ratio in the ceramic has also been given an important consideration in the production of PZT ceramics. This is because the MPB exists in between the ratio of Zr/Ti in the phase diagram. The effects of Zr/Ti ratio and those of different additives such as Mn, Sr, La and others on the structural and electrical properties of PZT ceramics were investigated extensively in various earlier studies (Nogas-Cwikel, 2011; Devi et al., 2012; Nguyen et al., 2014).

The perovskite structure is originally cubic with A^{2+} ion at the edge, B^{4+} ion at the centre and O^{2-} ion at the center face position, representing the cell. In order to improve dielectric, piezoelectric and mechanical properties, the PZT ceramics with perovskite structure (ABO_3) are usually substituted in A-sites or/and B-sites. The

major reasons for these improvement were due to the presence of cation vacancies during donor doped (soft dopant) while presence of oxygen vacancies in acceptor doped (hard dopant) (Frayssignes et al., 2004). Typically, soft dopant ceramics such as La, Nd, Sr, Sb, Bi, Ca and other rare earth always possess high permittivity and electromechanical coupling factor, which suitably serve as receiver type transducers, sensor and actuator application. The additives such as Nb_2O_5 and CaO are known as soft dopant because they decrease the coercive field and elastic modulus. Meanwhile, hard dopant ceramics such as K, Na, Fe and Mn are used as emission type transducer due to their high tensile strength and mechanical quality factor, as well as low loss (Yu et al., 2015). Hard dopant PZT can also withstand high electrical excitation which is suitable for high power application. Meanwhile, the additive of Fe_2O_3 and MnO_2 act as hard dopant because they increase the coercive field and elastic modulus (Ibrahim et al., 2003).

Many investigations have been done on altering the composition of the piezoelectric materials. The composition of PZT system has been altered with various dopants in order to improve electrical properties for high technology applications. Aside from altering the composition, the parameters of poling process (polarization) also contributed towards the electrical and mechanical properties of the system especially in dielectric and piezoelectric properties (Cavalcante et al., 2006; Kalem and Timucin, 2013; Kainz et al., 2016). In poling process, electric field and temperature have a significant effect on improving the electrical properties. Li et al. (2011), generally believed that temperature plays an important role during the poling process because it leads to the optimization of the piezoelectric properties. This is because during poling process the sufficient high electric field is applied to the ceramic sample, the domains undergo orientation and align the domains in the

allowable directions closest to the direction of applied field. After the removal of electric field, the orientation of domains is partially retained and ceramic exhibits the piezoelectric effect (Kholkin et al., 1998). Several researchers studied the effect of poling towards the properties of PZT ceramics especially in dielectric and piezoelectric properties. They claimed that the poling temperature and electric field strongly influence the conversion between electrical and mechanical energy (Jaitanong and Chaipanich, 2008; Prewitt and Jones, 2011; Yu et al., 2015).

PZT is widely used in cooling application such as actuators and sensors. The most commonly piezoelectric actuators is known as piezoelectric fan (Liu and Liaw, 2004). Previously, the conventional cooling system such as rotary fan and heat sink were used for thermal management of portable electronics devices. However, the piezoelectric fans are moving towards supplementing the cooling of stagnant areas and hot spots where the cooling of the rotational fan is less effective (Acikalin et al., 2004). Piezoelectric fans are capable of enhancing electric machine housing heat transfer and have been used in a number of applications, mainly in electronics cooling. However, their application to electrical machine cooling has not been previously considered and became a challenge (Gilson et al., 2013).

1.2 Problem Statement

The use of PZT ceramic system in industry has gained attention among researchers due to the good performance in piezoelectric properties. Even though many researchers studied about the lead-free piezoelectric materials due to toxicity, PZT systems still give the best performance especially in piezoelectric properties. PZT materials are well known in electronic applications for their good piezoelectric properties and are ideal candidates for making sensors and actuators (Ramana et al.,

2010). PZT is always modified with dopants for further improvising the electrical properties such as piezoelectric permittivity (d_{33}), electromechanical coupling factor (k_p) and dielectric permittivity (ϵ_r) that is required for specific applications. Therefore, various researchers have studied about the substitution of ions from dopant materials (Sr, Mn, Nb, La, Fe and other rare earth metals) in order to improve the densification and to enhance the dielectric and piezoelectric properties (Wu et al., 2013; Aleem et al., 2013; Bahanurddin et al., 2015; Kour et al., 2014).

Among the dopants, the behaviour of La^{3+} doping in PZT system shows an increment in aspects of the piezoelectric, dielectric and ferroelectric. However, the incorporation of La^{3+} in the PZT system profound effects on dielectric properties due to the growth inhibitions and caused of degradation of k_p (Pdungsap et al., 2005; Sahoo and Panda, 2013). They reported that the excess of La^{2+} was precipitated in the grain boundary and slowed the grain growth hence reduces the electrical properties. Another research was studied with co-doped two dopants material in the PZT system which were La^{3+} and Sr^{2+} in order to enhance its properties (Kalem et al., 2011). However, they found that when a higher composition of La^{3+} is used, the k_p was decreased due to growth inhibition. Meanwhile, Devi et al. (2012) claimed that the introduction of Sr^{2+} in lead lanthanum zirconate titanate (PLZT) decreased the dielectric permittivity and exhibited a maximum value of $\epsilon_r = 1523$. The decrease in the dielectric permittivity attributed partly to the increase of the compositional heterogeneity produced by a greater atomic diffusion and presence of lead vacancies.

Bahanurddin et al. (2015) also studied on La^{3+} and Sr^{2+} co-doped PZT via high energy planetary ball mill and shows good dielectric properties (dielectric permittivity was 5360) but the piezoelectric properties were not mentioned. Moreover, Siddiqui et al. (2017) profound effects of Li^+ on PLSZT but the d_{33} value

was decreased from 315 pC/N to 259 pC/N. However, the d_{33} and k_p was still indicated as a lower value for electronic device applications. According to Yorinaga et al. (1985), the higher d_{33} (>350 pC/N), k_p (>0.5) and ϵ_r are desirable for application of the electromechanical devices such as piezoelectric fan. High d_{33} and k_p in poled PZT ceramics are believed to arise from the motion of domain walls under the action of applied field or stress.

Apart from the doping process, the poling behaviour also plays an important role in obtaining better dielectric and piezoelectric properties. A few studies have been reported on poling parameters where referred to electric field, temperature and time taken for poling process (Li et al., 2011; Yu et al., 2015). Prewitt and Jones (2011) reported that temperature was the most influenced parameter in poling process due to domain wall motion was thermally activated at an elevated temperature. This would promote a higher degree of domain orientation, which leads to a larger developed polarization, and thus, increases the piezoelectric coefficients. However, the influences of poling parameter on piezoelectric coefficient are focusing only on undoped PZT system and no details studies on doped PZT.

Therefore, in this case, the poling behaviour of La^{3+} and Sr^{2+} co-doped PZT (PLSZT) was further investigated using Design of Experiment (DOE) concept to understand the poling parameter effects on the dielectric and piezoelectric properties. DOE was used to ensure the research or experiment in generating a valid, defensible, and supportable conclusions. Besides, a new dopant (CaCO_3) doped in PLSZT was also investigated to improve the electrical properties in PLSZT system. A Ca^{2+} ion proved that it would promote a polarization of the unit cell which results in increasing of remnant polarization. Thus, enhancing the dielectric and piezoelectric properties (Mohiddon and Yadav, 2008; Kour et al., 2014; Silva et al., 2015). Lead